

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	9316	semiconductor and ((thin adj film adj transistor) or tft) and (gate adj electrode)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM TDB	2002/01/26 11:23
2	BRS	L2	497	1 and taper\$3	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM TDB	2002/01/26 11:26
3	BRS	L3	138	2 and (ldd or (lightly adj doped adj drain))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM TDB	2002/01/26 11:27

	Comments	Error Definition	Errors
1			0
2			0
3			0